INTEGRATED CIRCUITS

DATA SHEET

74LV365Hex buffer/line driver (3-State)

Product specification Supersedes data of 1997 Mar 04 IC24 Data Handbook





Hex buffer/line driver (3-State)

74LV365

FEATURES

- Optimized for Low Voltage applications: 1.0 to 3.6V
- Accepts TTL input levels between V_{CC} = 2.7V and V_{CC} = 3.6V
- Typical V_{OLP} (output ground bounce) < 0.8V @ V_{CC} = 3.3V, $T_{amb} = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) > 2V @ V_{CC} = 3.3V, $T_{amb} = 25^{\circ}C$
- Non-inverting outputs
- Output capability: bus driver
- I_{CC} category: MSI

DESCRIPTION

The 74LV365 is a low-voltage CMOS device and is pin and function compatible 74HC/HCT365.

The 74LV365 is a hex non-inverting buffer/line driver with 3-State outputs. The 3-State outputs (nY) are controlled by the output enable inputs (OE1, OE2).

A HIGH on \overline{OE} n, causes the outputs to assume a high impedance OFF-state.

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay nA to nY	$C_L = 15pF$ $V_{CC} = 3.3V$	9	ns
C _I	Input capacitance		3.5	pF
C _{PD}	Power dissipation capacitance per buffer	Notes 1 and 2	40	pF

- 1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW)

 - P_D = C_{PD} × V_{CC}² × f_i + Σ (C_L × V_{CC}² × f_o) where: f_i = input frequency in MHz; C_L = output load capacitance in pF; f_o = output frequency in MHz; V_{CC} = supply voltage in V;
- $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs.}$
- 2. The condition is $V_I = GND$ to V_{CC}

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #	
16-Pin Plastic DIL	-40°C to +125°C	74LV365 N	74LV365 N	SOT38-4	
16-Pin Plastic SO	-40°C to +125°C	74LV365 D	74LV365 D	SOT109-1	
16-Pin Plastic SSOP Type II	–40°C to +125°C	74LV365 DB	74LV365 DB	SOT338-1	
16-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV365 PW	74LV365PW DH	SOT403-1	

PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION				
1, 15	OE1, OE2	Output enable inputs (active-LOW)				
2, 4, 6, 10, 12, 14	1A to 6A	Data inputs				
3, 5, 7, 9, 11, 13	1Y to 6Y	Data outputs				
8	GND	Ground (0V)				
16	V _{CC}	Positive supply voltage				

FUNCTION TABLE

	INPUTS		OUTPUT
OE1	OE2	nA	nY
L	L	L	L
L	L	Н	Н
Х	Н	Х	Z
Н	Х	Х	Z

H = HIGH voltage level

L = LOW voltage level

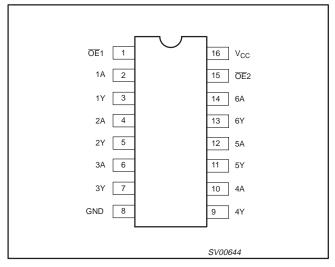
X = Don't care

Z = High impedance OFF-state

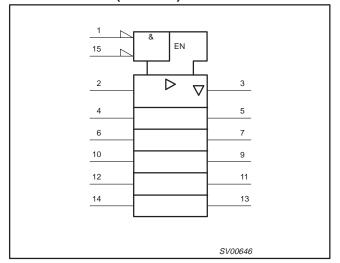
Hex buffer/line driver (3-State)

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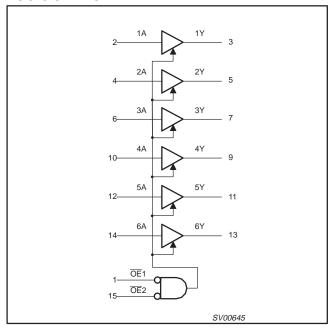
PIN CONFIGURATION



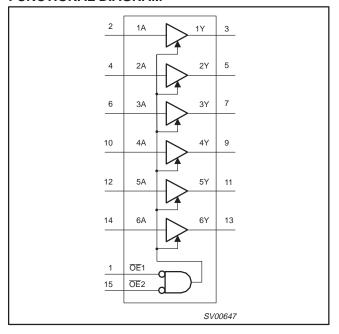
LOGIC SYMBOL (IEEE/IEC)



LOGIC SYMBOL



FUNCTIONAL DIAGRAM



Hex buffer/line driver (3-State)

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1	1.0	3.3	3.6	V
VI	Input voltage		0	_	V _{CC}	V
Vo	Output voltage		0	_	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C
t _r , t _f	Input rise and fall times	V _{CC} = 1.0V to 2.0V V _{CC} = 2.0V to 2.7V V _{CC} = 2.7V to 3.6V		- - -	500 200 100	ns/V

NOTE

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
±I _{IK}	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5V$	20	mA
±I _{OK}	DC output diode current	$V_{O} < -0.5 \text{ or } V_{O} > V_{CC} + 0.5V$	50	mA
±l _O	DC output source or sink current – bus driver outputs	$-0.5V < V_O < V_{CC} + 0.5V$	35	mA
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with –bus driver outputs		70	mA
T _{stg}	Storage temperature range		-65 to +150	°C
P _{tot}	Power dissipation per package -plastic DIL -plastic mini-pack (SO) -plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

^{1.} The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 3.6V.

^{1.} Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

^{2.} The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC CHARACTERISTICS FOR THE LV FAMILY

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V).

					LIMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	-4	0°C to +8	5°C	-40°C to	o +125°C	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	1
		V _{CC} = 1.2V	0.9			0.9		
V_{IH}	HIGH level Input voltage	V _{CC} = 2.0V	1.4			1.4		V
	Vollago	V _{CC} = 2.7 to 3.6V	2.0			2.0		1
		V _{CC} = 1.2V			0.3		0.3	
V_{IL}	LOW level Input voltage	V _{CC} = 2.0V			0.6		0.6	V
	Tonago	V _{CC} = 2.7 to 3.6V			0.8		0.8	1
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL}; -I_O = 100 \mu A$		1.2				
M	HIGH level output	$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	1.8	2.0		1.8		
V _{OH}	voltage; all outputs	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL;} -I_O = 100 \mu A$	2.5	2.7		2.5		1 '
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; -I_O = 100 \mu A$	2.8	3.0		2.8		
V _{OH}	HIGH level output voltage; BUS driver outputs	$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $-I_O = 8mA$	2.40	2.82		2.20		V
		$V_{CC} = 1.2V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0				
M	LOW level output	$V_{CC} = 2.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		0	0.2		0.2	
V _{OL}	voltage; all outputs	V_{CC} = 2.7V; V_I = V_{IH} or V_{IL} , I_O = 100 μ A		0	0.2		0.2] '
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}, I_O = 100 \mu A$		0	0.2		0.2	1
V _{OL}	LOW level output voltage; BUS driver outputs	$V_{CC} = 3.0V$; $V_I = V_{IH}$ or V_{IL} ; $I_O = 8mA$		0.20	0.40		0.50	V
I _I	Input leakage current	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND			1.0		1.0	μА
I _{OZ}	3-State output OFF-state current	V_{CC} = 3.6V; V_{I} = V_{IH} or V_{IL} ; V_{O} = V_{CC} or GND			5		10	μА
I _{CC}	Quiescent supply current; MSI	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND; $I_O = 0$			20.0		160	μА
Δl _{CC}	Additional quiescent supply current per input	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$			500		850	μА

NOTE:

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^{1.} All typical values are measured at $T_{amb} = 25$ °C.

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AC CHARACTERISTICS

 $\label{eq:gnd} \text{GND} = \text{OV}; \ t_{\text{f}} = t_{\text{f}} \leq \text{2.5ns}; \ C_{\text{L}} = \text{50pF}; \ R_{\text{L}} = 1 \text{K}\Omega$

			CONDITION			LIMITS					
SYMBOL	PARAMETER	WAVEFORM	CONDITION		40 to +85 °	С	-40 to -	+125 °C	UNIT		
			V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX			
			1.2	-	55	_	-	_			
.	Propagation delay	Figure 1	2.0	_	19	36	_	44	no		
t _{PHL} /t _{PLH}	nA to nY	Figure 1	2.7	-	14	26	-	33	ns		
			3.0 to 3.6	-	10 ²	21	-	26			
			1.2	_	85	_	_	_			
.	3-State output enable time	Figure 2	Figure 2	Figure 2	2.0	_	29	56	_	66	no
t _{PZH} /t _{PZL}	OEn to nY				rigure 2	rigule 2	2.7	_	21	41	-
			3.0 to 3.6	-	16 ²	33	-	39			
			1.2	-	100	_	-	_			
	3-State output disable time OEn to nY	Eiguro 2	2.0	-	36	66	-	78	no		
IPHZ/IPLZ		Figure 2	2.7	-	27	48	-	58	ns		
			3.0 to 3.6	-	21 ²	39	_	47			

1. All typical values are measured at $T_{amb} = 25^{\circ}C$

2. Typical values are measured at $V_{CC} = 3.3V$

AC WAVEFORMS

 V_{M} = 1.5V at $V_{CC}\,\geq\,2.7V$

 V_{M} = 0.5V * V_{CC} at V_{CC} < 2.7V V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

 $V_X = V_{OL} + 0.3V$ at $V_{CC} \ge 2.7V$

 $V_X = V_{OL} + 0.1 V_{CC}$ at $V_{CC} < 2.7 V$ $V_Y = V_{OH} - 0.3 V$ at $V_{CC} \ge 2.7 V$

 $V_Y = V_{OH} - 0.1 V_{CC}$ at $V_{CC} < 2.7 V$

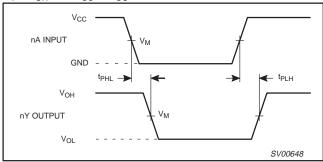


Figure 1. Input (nA) to output (nY) propagation delays.

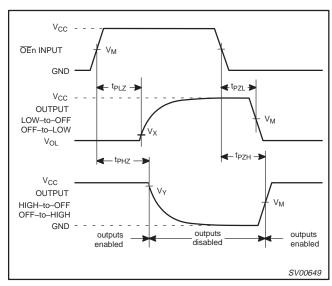


Figure 2. 3-State enable and disable times.

Hex buffer/line driver (3-State)

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TEST CIRCUIT

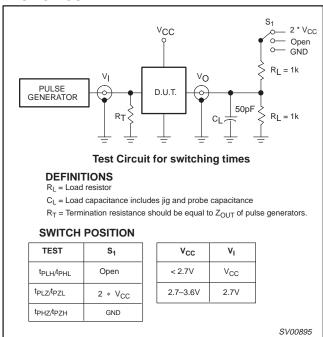


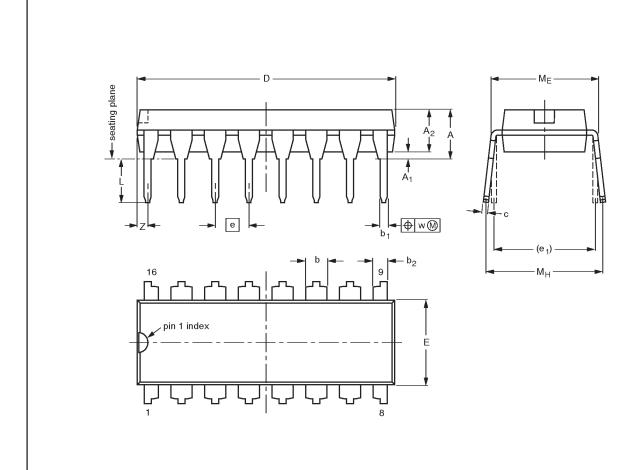
Figure 3. Load circuitry for switching times

Hex buffer/line driver (3-State)

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DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	c	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	Мн	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

scale

10 mm

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT38-4				□ •	92-11-17 95-01-14

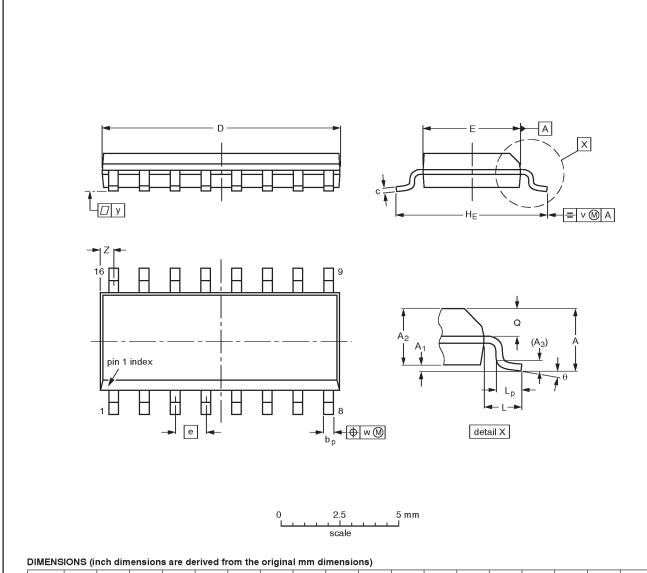
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Hex buffer/line driver (3-State)

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SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	Α1	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	٦	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.0098 0.0039		0.01	l	0.0098 0.0075	0.39 0.38	0.16 0.15	0.050	0.24 0.23	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

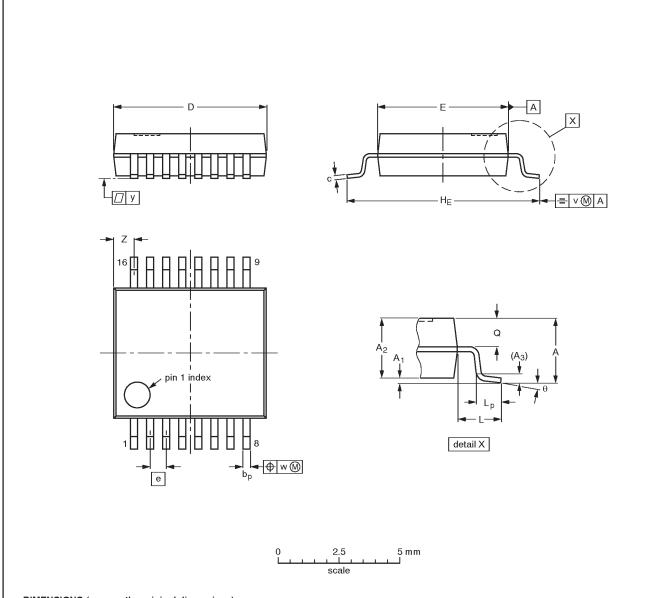
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE
SOT109-1	076E07\$	MS-012AC			91-08-13 95-01-23

Hex buffer/line driver (3-State)

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SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	рb	c	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Ø	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT338-1		MO-150AC				94-01-14 95-02-04

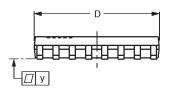
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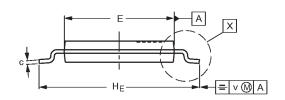
Hex buffer/line driver (3-State)

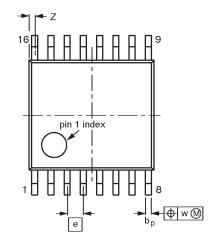
74LV365

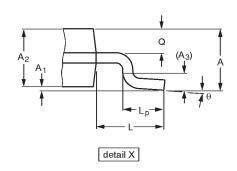
TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1











DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	рb	c	D ⁽¹⁾	E ⁽²⁾	Φ	HE	L	Lp	ø	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1930E DATE
SOT403-1		MO-153				-94-07-12- 95-04-04

Hex buffer/line driver (3-State)

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	DEFINITIONS						
Data Sheet Identification	Product Status	Definition					
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.					
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.					
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